



ZXTD720MC

DUAL 40V PNP LOW SATURATION SWITCHING TRANSISTOR

Features

- $V_{CEO} = -40V$
- $R_{SAT} = 104 \text{ m}\Omega$
- I_C = -3A Continuous Collector Current
- Low Equivalent On Resistance
- Low Saturation Voltage (-220mV @ -1A)
- hFE specified up to -3A
- Lead, Halogen, and Antimony Free/RoHS Compliant (Note 1)
- "Green" Devices (Note 2)

Mechanical Data

- Case: DFN3020B-8
- Case material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Rating 94V-0
- Terminals: Pre-Plated NiPdAu leadframe.
- Nominal package height: 0.8mm
- Moisture Sensitivity: Level 1 per J-STD-020
- Solderable per MIL-STD-202, Method 208
- Weight: 0.013 grams (approximate)

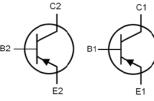
Applications

- **DC-DC** Converters
- Charging circuits
- Power switches
- Motor control
- **CCFL** Backlighting

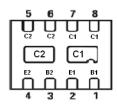
DFN3020B-8



DFN3020B-8



Device symbol



Pin Configuration

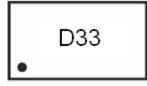
Ordering Information

Product	Status	Package	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTD720MCTA	Active	DFN3020B-8	D33	7	8	3000

Notes: 1. No purposefully added lead. Halogen and Antimony Free.

2. Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com

Marking Information



D33 = Product type Marking Code Dot denotes Pin 1



ZXTD720MC

Maximum Ratings

Parameter	Symbol	Limit	Unit
Collector-Base Voltage	V _{CBO}	-50	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-7.5	V
Peak Pulse Current	Ісм	-4	А
Continuous Collector Current (Notes a and b)	I _C	-3	A
Base Current	IB	-1	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation at $T_A = 25^{\circ}C$ (Notes a and f)	P	1.5	W
Linear Derating Factor	PD	12	mW/°C
Power Dissipation at $T_A = 25^{\circ}C$ (Notes b and f)	Р	2.45	W
Linear Derating Factor	PD	19.6	mW/°C
Power Dissipation at $T_A = 25^{\circ}C$ (Notes c and f)	Pn	1	W
Linear Derating Factor	FD	8	mW/°C
Power Dissipation at $T_A = 25^{\circ}C$ (Notes d and f)	Pn	1.13	W
Linear Derating Factor	10	9	mW/°C
Power Dissipation at $T_A = 25^{\circ}C$ (Notes d and g)	Pn	1.7	W
Linear Derating Factor	10	13.6	mW/°C
Power Dissipation at $T_A = 25^{\circ}C$ (Notes e and g)	PD	3	W
Linear Derating Factor	FD	24	mW/°C
Junction to Ambient (Notes a and f)	$R_{ ext{ heta}JA}$	83.3	°C/W
Junction to Ambient (Notes b and f)	R ₀ JA	51	°C/W
Junction to Ambient (Notes c and f)	$R_{ ext{ heta}JA}$	125	°C/W
Junction to Ambient (Notes d and f)	R _{0JA}	111	°C/W
Junction to Ambient (Notes d and g)	R ₀ JA	73.5	°C/W
Junction to Ambient (Notes e and g)	R _{0JA}	41.7	°C/W
Junction Temperature	TJ	150	°C
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

a. For a dual device surface mounted on 8 sq cm single sided 2 oz copper on FR4 PCB, in still air conditions with all exposed pads attached. The copper area is split down the centre line into two separate areas with one half connected to each half of the dual device.

b. Measured at t <5 secs for a dual device surface mounted on 8 sq cm single sided 2 oz copper on FR4 PCB, in still air conditions with all exposed pads

attached. The copper area is split down the centre line into two separate areas with one half connected to each half of the dual device. c. For a dual device surface mounted on 8 sq cm single sided 2 oz copper on FR4 PCB, in still air conditions with minimal lead connections only. d. For a dual device surface mounted on 10 sq cm single sided 1 oz copper on FR4 PCB, in still air conditions with all exposed pads attached. The

copper area is split down the centre line into two separate areas with one half connected to each half of the dual device. e. For a dual device surface mounted on 85 sq cm single sided 2 oz copper on FR4 PCB, in still air conditions with all exposed pads attached. The copper area is split down the centre line into two separate areas with one half connected to each half of the dual device.

f. For a dual device with one active die.

g. For dual device with 2 active die running at equal power.

Notes:





3.5 10 4. 25°C 2oz Cu Max Power Dissipation (W 3.0 Collector Qurrent (A) Note (e)(g) 2.5 20z Cu Note (a)(f) 2.0 1oz Cu 100ms Note (d)(g) -1.5 0.1 10ms 1.0 Note (a)(f) 1ms 100us 1oz Cu 1 0.5 0.01 Single Pulse, T_m=25°C Note (d)(f) 0.0L 0.1 50 25 75 100 125 10 150V_{ce} Collector-Emitter Voltage (V) Temperature (°C) Safe Operating Area **Derating Curve** 225 TITI Note (a)(f) 200 80 Thermal Resistance (°C/M) Thermal Resistance (°C/M) 1oz copper 175 Note (f) 1oz coppe Note (g) 150 60 125 D=0.5 M 100 40 75 Single Pulse 2oz copper D=0.2 50 20 Note (f) D=0.05 2oz copper 25 Note (g) D=0.1 8 foou 1m 10m 100m 10 100 1k 100 Pulse Width (s) Board Cu Area (socm) Transient Thermal Impedance Thermal Resistance v Board Area 3.5 25°C 2oz copper 3.0 =150°C Note (g) P₀Dissipation (W) Continuous 2.5 THI 2oz coppe 20 m Note (f) 1.5 1.0 Toz copper 0.5 1oz copper Note (g) Note (f) 0.9L 0.1 10 100 Board Cu Area (sqcm) Power Dissipation v Board Area

Thermal Characteristics and Derating information





Electrical Characteristics @T_A = 25°C unless otherwise specified

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Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-50	-80	-	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 3)	V _{(BR)CEO}	-40	-70	-	V	$I_{C} = -10 \text{mA}$
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-7.5	-8.5	-	V	I _E = -100μA
Collector Cutoff Current	I _{CBO}	-	-	-25	nA	V _{CB} = -16V
Emitter Cutoff Current	I _{EBO}	-	-	-25	. nA	$V_{EB} = -6V$
Collector Emitter Cutoff Current	ICES	-	-	-25	nA	V _{CES} = -10V
		300	480	-	-	I _C = -10mA, V _{CE} = -2V
	3) h _{FE}	300	450	-	-	$I_{C} = -100 \text{mA}, V_{CE} = -2 \text{V}$
Static Forward Current Transfer Ratio (Note 3)		180	290	-	-	$I_{C} = -1A, V_{CE} = -2V$
		60	130	-	-	I _C = -1.5A, V _{CE} = -2V
		12	22	-	-	$I_{C} = -3A, V_{CE} = -2V$
		-	-25	-40		I _C =- 0.1A, I _B = -10mA
	V _{CE(sat)}	-	-150	-220		I _C = -1A, I _B = -50mA
Collector-Emitter Saturation Voltage (Note 3)		-	-195	-300	mV	I _C = -1.5A, I _B = -100mA
		-	-210	-300		$I_{C} = -2A, I_{B} = -200 \text{mA}$
		-	-260	-370		I _C = -2.5A, I _B = -250mA
Base-Emitter Turn-On Voltage (Note 3)	V _{BE(on)}	-	-0.89	-0.95	V	I _C = -2.5A, V _{CE} = -2V
Base-Emitter Saturation Voltage (Note 3)	V _{BE(sat)}	-	-0.97	-1.05	V	I _C = -2.5A, I _B = -250mA
Output Capacitance	C _{obo}	-	19	25	pF	V _{CB} = -10V. f = 1MHz
Transition Frequency	f _T	150	190	-	MHz	V _{CE} = -10V, I _C = -50mA, f = 100MHz
Turn-on Time	ton	-	40	-	ns	V _{CC} = -15V, I _C = -0.75A
Turn-off Time	t _{off}	-	435	-	ns	$I_{B1} = I_{B2} = -15mA$

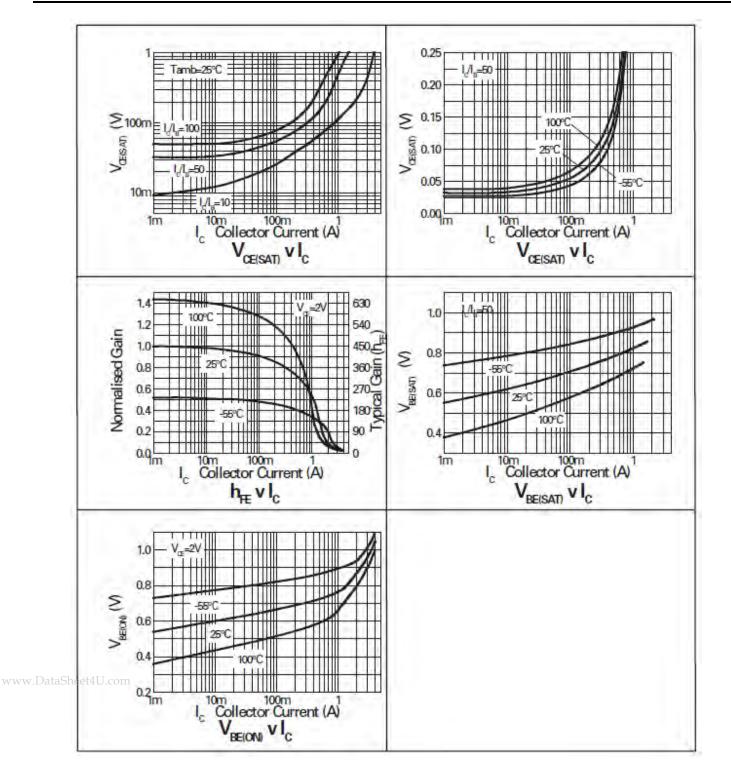
Notes: 3. Measured under pulsed conditions. Pulse width = 300 μ s. Duty cycle $\leq 2\%$

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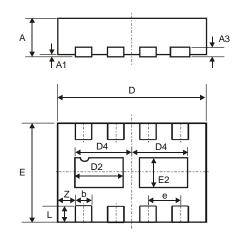
Typical Characteristics





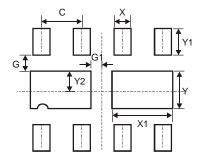


Package Outline Dimensions



DFN3020B-8						
Dim	Min	Max	Тур			
Α	0.77	0.83	0.80			
A1	0	0.05	0.02			
A3	-	-	0.15			
b	0.25	0.35	0.30			
D	2.95	3.075	3.00			
D2	0.82	1.02	0.92			
D4	1.01	1.21	1.11			
е	-	-	0.65			
Е	1.95	2.075	2.00			
E2	0.43	0.63	0.53			
L	0.25	0.35	0.30			
Ζ	-	-	0.375			
All Dimensions in mm						

Suggested Pad Layout



Dimensions	Value (in mm)		
С	0.650		
G	0.285		
G1	0.090		
Х	0.400		
X1	1.120		
Y	0.730		
Y1	0.500		
Y2	0.365		

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